<u>Linear Regulator</u> - Wide Input Voltage Range, Ultra-Low Iq, High PSRR

10 mA

The NCP785A is a high–performance linear regulator, offering a very wide operating input voltage range of up to 450 V DC, with an output current of up to 10 mA.

Ideal for high input voltage applications such as industrial and home metering, home appliances. The NCP785A family offers $\pm 5\%$ initial accuracy, extremely high-power supply rejection ratio and ultra-low quiescent current. The NCP785A is optimized for high-voltage line and load transients, making this part ideal for harsh environment applications.

The NCP785A is offered in fixed output voltage options 3.3 V, 5.0 V, 12 V and 15 V.

SOT-89 package offers good thermal performance and help to minimize the solution size.

Features

• Wide Input Voltage Range:

DC: Up to 450 V

AC: 85 V to 260 V (half-wave rectifier and 2.2 µF capacitor)

- 10 mA Guaranteed Output Current
- Ultra Low Quiescent Current: Typ. 10 μ A (V_{OUT} \leq 5 V)
- ±5% Accuracy Over Full Load, Line and Temperature Variations
- Ultra-high PSRR: 70 dB at 60 Hz, 90 dB at 100 kHz
- Stable with Ceramic Output Capacitor 22 µF MLCC
- Thermal Shutdown and Current Limit Protection
- Available in Thermally Enhanced SOT89-3 Package
- This is a Pb–Free Device

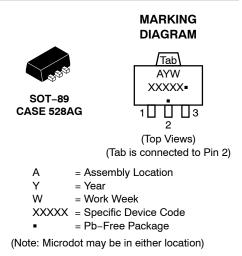
Typical Applications

- Industrial Applications, Home Appliances
- Home Metering / Network Application
- Off-line Power Supplies



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ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 9 of this data sheet.

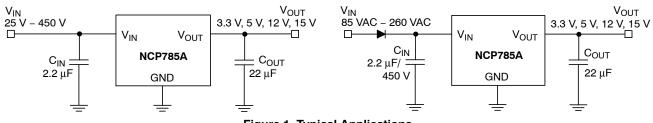


Figure 1. Typical Applications

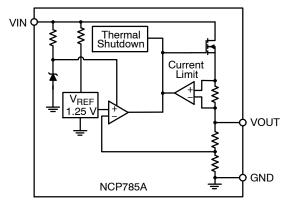


Figure 2. Simplified Internal Block Diagram

Table 1. PIN FUNCTION DESCRIPTION

Pin No. (SOT–89)	Pin Name	Description			
1	VIN	Supply Voltage Input. Connect 2.2 μF capacitor from VIN to GND.			
2, Tab	GND	Ground connection.			
3	VOUT	Regulator Output. Connect 22 μF or larger MLCC capacitor from VOUT to GND.			

Table 2. ABSOLUTE MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Input Voltage (Note 1)	V _{IN}	–0.3 to 700	V
Output Voltage	V _{OUT}	–0.3 to 18	V
Maximum Junction Temperature	T _{J(MAX)}	150	°C
Storage Temperature	T _{STG}	–55 to 150	°C
ESD Capability, Human Body Model (All pins except HV pin no.1) (Note 2)	ESD _{HBM}	2000	V
ESD Capability, Machine Model (Note 2)	ESD _{MM}	200	V

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Peak 650 V max 1 ms non repeated for 1 s

2. This device series incorporates ESD protection and is tested by the following methods:

ESD Human Body Model tested per AEC-Q100-002 (EIA/JÉSD22-A114)

ESD Machine Model tested per AEC-Q100-003 (EIA/JESD22-A115)

Latch-up Current Maximum Rating tested per JEDEC standard: JESD78.

Table 3. THERMAL CHARACTERISTICS

Rating	Symbol	Value	Unit
Thermal Characteristics, SOT-89 Thermal Resistance, Junction-to-Air	$R_{ hetaJA}$	79	°C/W

Parameter	Test Conditions	Symbol	Min	Тур	Max	Unit
Operating Input Voltage DC		V _{IN}	25		450	V
Output Voltage Accuracy	$T_J = 25^{\circ}C$, lout = 100 μ A, 25 V \leq Vin \leq 450 V	V _{OUT}	3.1515	3.3	3.4485	V
	$-40^\circ C \leq T_J \leq 85^\circ C, \mbox{ lout}$ = 100 $\mu A,$ 25 V \leq Vin \leq 450 V	V _{OUT}	3.135	3.3	3.465	V
Line Regulation	25 V \leq Vin \leq 450 V, lout = 100 μA	Reg _{LINE}	-0.5	0.2	+0.5	%
Load Regulation	100 $\mu A \leq I_{OUT} \leq$ 10 mA, Vin = 35 V	Reg _{LOAD}	-1.0	0.6	+1.0	%
Maximum Output Current (Note 4)	$35 \text{ V} \le \text{Vin} \le 450 \text{ V}$	I _{OUT}	10.5			mA
Quiescent Current	$I_{OUT} = 0, 25 \text{ V} \le \text{Vin} \le 450 \text{ V}$	Ι _Q		7.5	14	μA
Ground Current (Note 4)	$\begin{array}{l} 25 \text{ V} \leq \text{Vin} \leq 450 \text{ V} \\ 0 < I_{OUT} \leq 10 \text{ mA} \end{array}$	I _{GND}			15	μΑ
Power Supply Rejection Ratio		PSRR		70		dB
Noise	$ f = 100 \text{ Hz to } 100 \text{ kHz} \\ Vin = 340 \text{ V}_{DC}, \text{ lout} = 100 \mu\text{A} $	V _{NOISE}		240		μVrms
Thermal Shutdown Temperature (Note 5)	Temperature increasing from $T_J = +25^{\circ}C$	T _{SD}		145		°C
Thermal Shutdown Hysteresis (Note 5)	Temperature falling from T _{SD}	T _{SDH}	-	10	-	°C

$\textbf{Table 4. ELECTRICAL CHARACTERISTICS, V_{OUT} = \textbf{3.3 V} (-40^{\circ}\text{C} \leq \text{T}_{J} \leq 85^{\circ}\text{C}; \text{ V}_{\text{IN}} = 340 \text{ V}; \text{ I}_{\text{OUT}} = 100 \ \mu\text{A}, \text{ C}_{\text{IN}} = 2.2 \ \mu\text{F}, \text{ I}_{\text{OUT}} = 100 \ \mu\text{A}, $	
C_{OUT} = 22 µF, unless otherwise noted. Typical values are at T _J = +25°C.) (Note 3)	

Table 5. ELECTRICAL CHARACTERISTICS, V_{OUT} = 5.0 V (-40°C \leq T_J \leq 85°C; V_{IN} = 340 V; I_{OUT} = 100 μ A, C_{IN} = 2.2 μ F, C_{OUT} = 22 μ F, unless otherwise noted. Typical values are at T_J = +25°C.) (Note 3)

Parameter	Test Conditions		Symbol	Min	Тур	Max	Unit
Operating Input Voltage DC			V _{IN}			450	V
Output Voltage Accuracy	$T_{J} = 25^{\circ}C$, lout = 100 μ A, 50 V s	≤ Vin ≤ 450 V	V _{OUT}	4.775	5.0	5.225	V
	$-40^\circ C \leq T_J \leq 85^\circ C, \mbox{ lout}$ = 100 μ 50 V \leq Vin \leq 450 V	A,	V _{OUT}	4.75	5.0	5.25	V
Line Regulation	50 V \leq Vin \leq 450 V, lout = 100 μ	A	Reg _{LINE}	-0.5	0.2	+0.5	%
Load Regulation	100 μ A \leq I _{OUT} \leq 10 mA, Vin = 5	5 V	Reg _{LOAD}	-1.0	0.62	+1.0	%
Maximum Output Current (Note 4)	55 V \leq Vin \leq 450 V		I _{OUT}	10.5			mA
Quiescent Current	I_{OUT} = 0, 50 V \leq Vin \leq 450 V		Ι _Q		16	21	μA
Ground Current (Note 4)	50 V \leq Vin \leq 450 V 0 $<$ I _{OUT} \leq 10 mA		I _{GND}			23	μA
Power Supply Rejection Ratio	$\label{eq:Vin} \begin{array}{l} \text{Vin} = 340 \; \text{V}_{DC} + 1 \; \text{Vpp} \\ \text{modulation, lout} = 100 \; \mu\text{A} \end{array}$	f = 1 kHz	PSRR		70		dB
Noise	f = 100 Hz to 100 kHz Vin = 340 V _{DC} , lout = 100 μA		V _{NOISE}		300		μVrms
Thermal Shutdown Temperature (Note 5)	Temperature increasing from $T_J = +25^{\circ}C$		T _{SD}		145		°C
Thermal Shutdown Hysteresis (Note 5)	Temperature falling from T _{SD}		T _{SDH}	-	10	-	°C

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

3. Performance guaranteed over the indicated operating temperature range by design and/or characterization production tested at T_J = T_A =

25°C. Low duty cycle pulse techniques are used during testing to maintain the junction temperature as close to ambient as possible. A proper heatsinking and/or low duty cycle pulse techniques are used to operate the device within the Safe Operating Area.
Guaranteed by design

Parameter	Test Conditions		Symbol	Min	Тур	Мах	Unit
perating Input Voltage DC		V _{IN}	55		450	V	
Output Voltage Accuracy	T_{J} = 25°C, lout = 100 $\mu A,$ 55 V \leq	$Vin \le 450 V$	V _{OUT}	11.460	12	12.540	V
	$\begin{array}{l} -40^{\circ}C \leq T_J \leq 85^{\circ}C, \mbox{ lout} = 100 \ \mu\text{A} \\ 55 \ V \leq Vin \leq 450 \ V \end{array}$	$-40^\circ C \leq T_J \leq 85^\circ C, \mbox{ lout}$ = 100 $\mu A,$ 55 V \leq Vin \leq 450 V		11.4	12	12.6	V
Line Regulation	55 V \leq Vin \leq 450 V, lout = 100 μ A	١	Reg _{LINE}	-0.5	0.1	+0.5	%/V
Load Regulation	100 μ A \leq I _{OUT} \leq 10 mA, Vin = 65	V	Reg _{LOAD}	-1.0	0.66	+1.0	%
Maximum Output Current (Note 7)	$55 \text{ V} \le \text{Vin} \le 450 \text{ V}$		I _{OUT}	10.5			mA
Quiescent Current	$I_{OUT} = 0,55 \text{ V} \le \text{Vin} \le 450 \text{ V}$		Ι _Q		17	22	μΑ
Ground Current (Note 7)	55 V \leq Vin \leq 450 V 0 < I _{OUT} \leq 10 mA		I _{GND}			25	μΑ
Power Supply Rejection Ratio	$\label{eq:Vin} \begin{array}{l} \text{Vin} = 340 \ \text{V}_{DC} + 1 \ \text{Vpp} \\ \text{modulation, lout} = 100 \ \mu\text{A} \end{array}$				70		dB
Noise	f = 100 Hz to 100 kHz Vin = 340 V _{DC} , lout = 100 μA		V _{NOISE}		420		μVrms
Thermal Shutdown Temperature (Note 8)	Temperature increasing from T_J = +25°C		T _{SD}		145		°C
Thermal Shutdown Hysteresis (Note 8)	Temperature falling from T _{SD}		T _{SDH}	-	10	-	°C

Table 6. ELECTRICAL CHARACTERISTICS, V_{OUT} = 12 V (-40°C \leq T_J \leq 85°C; V_{IN} = 340 V; I_{OUT} = 100 μ A, C_{IN} = 2.2 μ F, C_{OUT} = 22 µF, unless otherwise noted. Typical values are at T_J = +25°C.) (Note 6)

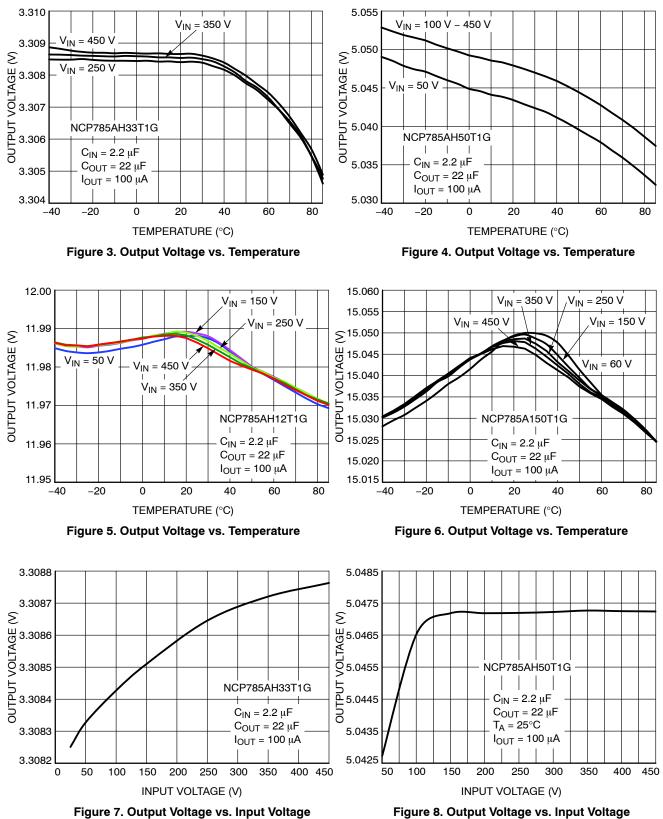
Table 7. ELECTRICAL CHARACTERISTICS, V_{OUT} = 15 V (-40°C $\leq T_J \leq$ 85°C; V_{IN} = 340 V; I_{OUT} = 100 μ A, C_{IN} = 2.2 μ F, C_{OUT} = 22 μ F, unless otherwise noted. Typical values are at T_J = +25°C.) (Note 6)

Parameter	Test Conditions		Symbol	Min	Тур	Мах	Unit
Operating Input Voltage DC			V _{IN}			450	V
Output Voltage Accuracy	$T_{J} = 25^{\circ}C$, lout = 100 μ A, 60 V s	≤ Vin ≤ 450 V	V _{OUT}	14.325	15	15.675	V
	$-40^\circ C \leq T_J \leq 85^\circ C, \mbox{ lout}$ = 100 μ 60 V \leq Vin \leq 450 V	A,	V _{OUT}	14.25	15	15.75	V
Line Regulation	60 V \leq Vin \leq 450 V, lout = 100 μ	A	Reg _{LINE}	-0.5	0.1	+0.5	%/V
Load Regulation	100 μ A \leq I _{OUT} \leq 10 mA, Vin = 6	5 V	Reg _{LOAD}	-1.0	0.66	+1.0	%
Maximum Output Current (Note 7)	$65 \text{ V} \le \text{Vin} \le 450 \text{ V}$		I _{OUT}	10.5			mA
Quiescent Current	$I_{OUT} = 0, 60 \text{ V} \le \text{Vin} \le 450 \text{ V}$		Ι _Q		18	22	μA
Ground Current (Note 7)	60 V \leq Vin \leq 450 V 0 $<$ I _{OUT} \leq 10 mA		I _{GND}			25	μA
Power Supply Rejection Ratio	$\label{eq:Vin} \begin{array}{l} \text{Vin} = 340 \; \text{V}_{DC} + 1 \; \text{Vpp} \\ \text{modulation, lout} = 100 \; \mu\text{A} \end{array}$				70		dB
Noise	f = 100 Hz to 100 kHz Vin = 340 V _{DC} , lout = 100 μA		V _{NOISE}		500		μVrms
Thermal Shutdown Temperature (Note 8)	Temperature increasing from $T_J = +25^{\circ}C$		T _{SD}		145		°C
Thermal Shutdown Hysteresis (Note 8)	Temperature falling from T _{SD}		T _{SDH}	-	10	-	°C

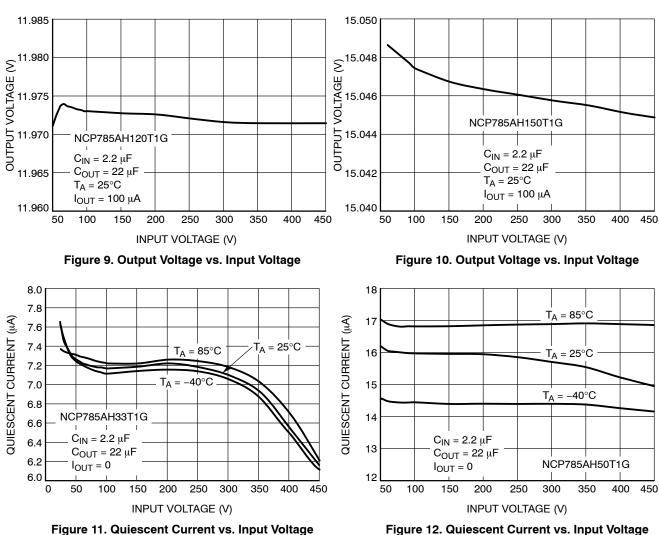
Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

6. Performance guaranteed over the indicated operating temperature range by design and/or characterization production tested at T_J = T_A =

25°C. Low duty cycle pulse techniques are used during testing to maintain the junction temperature as close to ambient as possible. 7. A proper heatsinking and/or low duty cycle pulse techniques are used to operate the device within the Safe Operating Area.

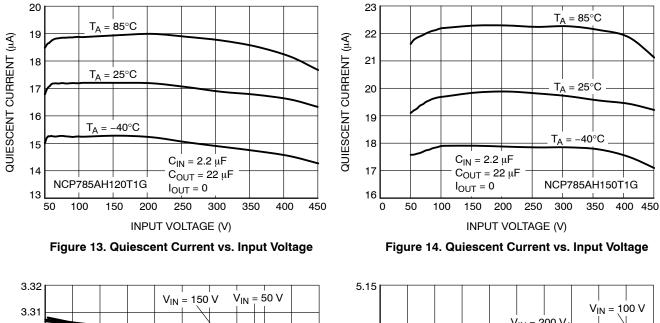


TYPICAL CHARACTERISTICS

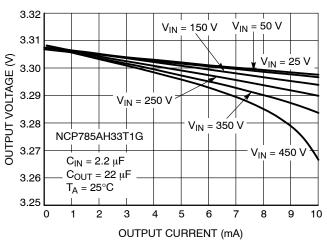


TYPICAL CHARACTERISTICS

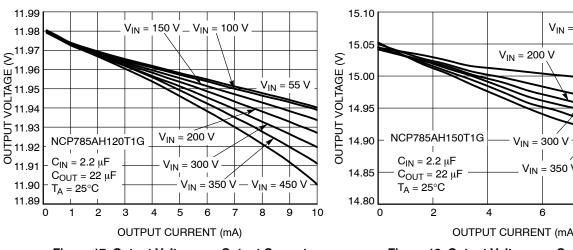
Figure 11. Quiescent Current vs. Input Voltage



TYPICAL CHARACTERISTICS











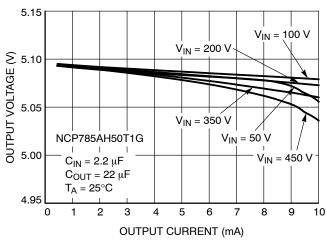
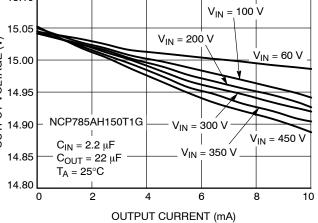
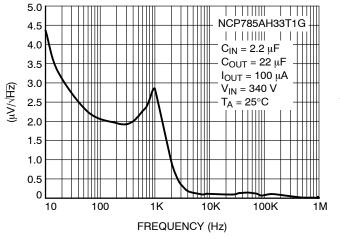


Figure 16. Output Voltage vs. Output Current







TYPICAL CHARACTERISTICS

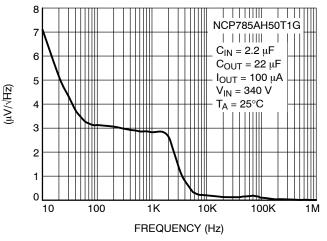


Figure 19. Output Noise Density vs. Frequency



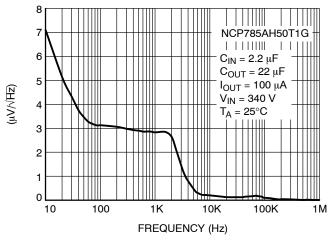


Figure 21. Output Noise Density vs. Frequency

25 NCP785AH150T1G 20 $C_{IN} = 2.2 \; \mu F$ C_{OUT} = 22 μ F $I_{OUT} = 100 \ \mu A$ 15 (μV//Hz) V_{IN} = 340 V T_A = 25°C 10 5 0 10 100 1K 10K 100K 1M FREQUENCY (Hz)

Figure 22. Output Noise Density vs. Frequency

APPLICATION INFORMATION

The typical application circuit for the NCP785A device is shown below.

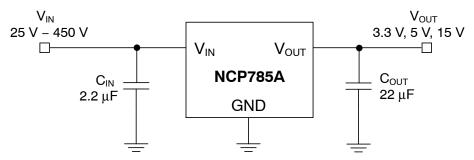


Figure 23. Typical Application Schematic

Input Decoupling (C1)

A 1 μ F capacitor either ceramic or electrolytic is recommended and should be connected close to the input pin of NCP785A. Higher value 2.2 μ F is necessary to sustain the required minimum input voltage at full load for AC voltage as low as 85 V with half wave rectifier.

Output Decoupling (C2)

The NCP785A Regulator does not require any specific Equivalent Series Resistance (ESR). Thus capacitors exhibiting ESRs ranging from a few m Ω up to 0.5 Ω can be used safely. The minimum decoupling value is 22 μ F. The regulator accepts ceramic chip capacitors as well as tantalum devices or low ESR electrolytic capacitors. Larger values improve noise rejection and load transient response.

Layout Recommendations

Please be sure the V_{IN} and GND lines are sufficiently wide. When the impedance of these lines is high, there is a chance to pick up noise or to cause the malfunction of regulator.

Set external components, especially the output capacitor, as close as possible to the circuit, and make leads as short as possible.

Thermal

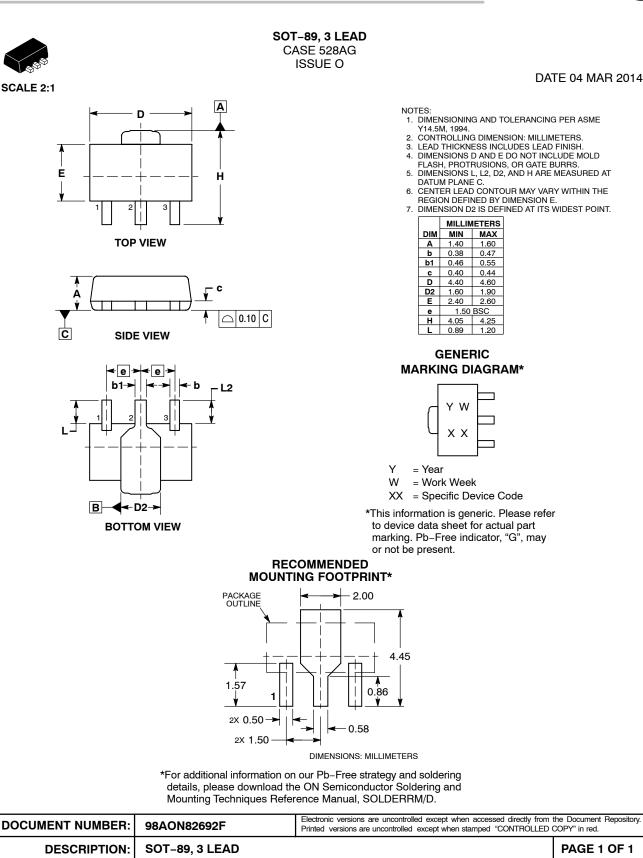
As power across the NCP785A increases, it might become necessary to provide some thermal relief. The maximum power dissipation supported by the device is dependent upon board design layout and used package. Mounting pad configuration on the PCB, the board material, and also the ambient temperature affect the rate of temperature rise for the part. This is stating that when the NCP785A has good thermal conductivity through the PCB, the junction temperature will be relatively low with high power dissipation applications.

ORDERING INFORMATION

Part Number	Output Voltage	Marking	Package	Shipping [†]		
NCP785AH33T1G	3.3 V	AA				
NCP785AH50T1G	5 V	AC	SOT-89	1000 / Tana & Daal		
NCP785AH120T1G	12 V	AJ	(Pb-Free)	1000 / Tape & Reel		
NCP785AH150T1G	15 V	AD				

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.





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